

Day : Wednesday

PALM INTRANETDate: 6/28/2006
Time: 06:35:07**Inventor Name Search Result**

Your Search was:

Last Name = MITAMURA

First Name = NOBUAKI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
07557574	5030017	150	07/24/1990	ROLLING BEARING	MITAMURA, NOBUAKI
07560445	5084116	150	07/31/1990	ROLLING CONTACT ELEMENT STEEL AND ROLLING BEARING MADE THEREOF	MITAMURA, NOBUAKI
07572480	5085733	150	08/23/1990	ROLLING CONTACT PARTS STEEL AND ROLLING BEARING MADE THEREOF	MITAMURA, NOBUAKI
07915503	Not Issued	161	07/20/1992	BALL AND ROLLER BEARING	MITAMURA, NOBUAKI
07946638	5338377	150	09/18/1992	BALL-AND-ROLLER BEARING	MITAMURA, NOBUAKI
08134588	5427457	150	10/12/1993	ROLLING BEARING	MITAMURA, NOBUAKI
08242668	5413643	150	05/13/1994	ROLLING BEARING	MITAMURA, NOBUAKI
08374179	Not Issued	166	01/18/1995	TOROIDAL-TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
08512419	5660647	150	08/08/1995	ROLLING BEARING WITH IMPROVED WEAR RESISTANCE	MITAMURA, NOBUAKI
08519643	5626974	150	08/25/1995	ROLLING BEARING FOR USE UNDER HIGH TEMPERATURE CONDITIONS	MITAMURA, NOBUAKI
08536773	5672014	150	09/29/1995	ROLLING BEARINGS	MITAMURA, NOBUAKI
08542828	5853660	150	10/13/1995	A ROLLING BEARING MADE OF IMPROVED BEARING STEEL	MITAMURA, NOBUAKI
08683195	5958155	150	07/18/1996	PROCESS FOR PRODUCING	MITAMURA,

				THIN FILM	NOBUAKI
<u>08745635</u>	5855531	150	11/08/1996	COMPONENT PARTS OF A TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION HAVING IMPROVED LIFE	MITAMURA, NOBUAKI
<u>08763883</u>	5887015	150	12/11/1996	HEATER MECHANISM FOR CRYSTAL PULLING APPARATUS	MITAMURA, NOBUAKI
<u>08877950</u>	5989694	150	06/17/1997	ROLLING BEARING	MITAMURA, NOBUAKI
<u>08955294</u>	Not Issued	164	10/21/1997	ROLLING BEARING MADE OF IMPROVED BEARING STEEL	MITAMURA, NOBUAKI
<u>09098980</u>	6171414	150	06/17/1998	ROLLING BEARING	MITAMURA, NOBUAKI
<u>09108174</u>	6174257	150	07/01/1998	TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
<u>09181911</u>	6174258	150	10/29/1998	TOROIDAL-TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
<u>09183630</u>	6066068	150	10/30/1998	TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
<u>09187607</u>	6165100	150	11/06/1998	HIGH-CLEANNESS STEEL AND TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION INCLUDING COMPONENTS SUCH AS INPUT/OUTPUT DISCS, POWER ROLLER AND CAM DISC USING THE HIGH-CLEANNESS STEEL	MITAMURA, NOBUAKI
<u>09226032</u>	6174085	150	01/05/1999	LINEAR GUIDE BEARING DEVICE	MITAMURA, NOBUAKI
<u>09235052</u>	6196946	150	01/21/1999	POWER ROLLER BEARING OF TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION AND METHOD OF MANUFACTURING POWER ROLLER BEARING OF TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI

09245931	Not Issued	161	02/08/1999	TEMPERATURE-INDEPENDENT OPTICAL ELEMENT	MITAMURA, NOBUAKI
09272731	6210542	150	11/04/1998	PROCESS FOR PRODUCING THIN FILM, THIN FILM AND OPTICAL INSTRUMENT INCLUDING THE SAME	MITAMURA, NOBUAKI
09339238	6332714	150	06/24/1999	INDUCTION-HARDENED ROLLING BEARING DEVICE	MITAMURA, NOBUAKI
09344380	6328669	150	06/25/1999	TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
09349204	6176806	150	07/07/1999	CAM DISK FOR TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
09358554	6478894	150	07/22/1999	ROLLING BEARING	MITAMURA, NOBUAKI
09379748	6152605	150	08/24/1999	BALL BEARING	MITAMURA, NOBUAKI
09401917	6358440	150	09/23/1999	PROCESS FOR PRODUCING THIN FILM, THIN FILM AND OPTICAL INSTRUMENT INCLUDING THE SAME	MITAMURA, NOBUAKI
09697179	6829053	150	10/27/2000	AIRGAP TYPE ETALON AND APPARATUS UTILIZING THE SAME	MITAMURA, NOBUAKI
09886122	6413188	150	06/22/2001	TOROIDAL TYPE CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
09939566	6646805	150	08/28/2001	APPARATUS FOR VARIABLE WAVELENGTH DISPERSION AND WAVELENGTH DISPERSION SLOPE	MITAMURA, NOBUAKI
09957413	6426022	150	09/20/2001	PROCESS FOR PRODUCING THIN FILM, THIN FILM AND OPTICAL INSTRUMENT INCLUDING THE SAME	MITAMURA, NOBUAKI
09984396	6807335	150	10/30/2001	WAVELENGTH CHARACTERISTIC VARIABLE APPARATUS	MITAMURA, NOBUAKI
10061307	6826318	150	02/04/2002	VARIABLE POLARIZATION PLANE ROTATOR AND OPTICAL DEVICE USING SAME	MITAMURA, NOBUAKI
10164438	6900940	150	06/10/2002	OPTICAL APPARATUS AND	MITAMURA,

				DEVICE	NOBUAKI
<u>10278868</u>	Not Issued	41	10/24/2002	Device using a virtually-imaged phased array (VIPA) with an improved transmission wave characteristic of output light	MITAMURA, NOBUAKI
<u>10286779</u>	6862126	150	11/04/2002	TRANSMISSION WAVELENGTH CHARACTERISTICS VARIABLE OPTICAL ELEMENT, AND WAVELENGTH CHARACTERISTICS VARIABLE APPARATUS, OPTICAL AMPLIFIER, OPTICAL TRANSMISSION SYSTEM, AND CONTROL METHOD OF TRANSMISSION WAVELENGTH CHARACTERISTICS, USING SAME	MITAMURA, NOBUAKI
<u>10310900</u>	Not Issued	93	12/06/2002	ROLLING BEARING	MITAMURA, NOBUAKI
<u>10340842</u>	6909537	150	01/13/2003	DISPERSION COMPENSATOR WHOSE TRANSMISSION BAND IS FLATTENED	MITAMURA, NOBUAKI
<u>10341380</u>	6807008	150	01/14/2003	WAVELENGTH DISPERSION GENERATION APPARATUS, MULTI-FACED MIRROR USED FOR WAVELENGTH DISPERSION GENERATION APPARATUS, AND METHOD FOR MANUFACTURING THEREOF	MITAMURA, NOBUAKI
<u>10351376</u>	7016096	150	01/27/2003	TRANSMISSION WAVELENGTH CHARACTERISTICS VARIABLE OPTICAL ELEMENT, AND WAVELENGTH CHARACTERISTICS VARIABLE APPARATUS, OPTICAL AMPLIFIER, AND OPTICAL TRANSMISSION SYSTEM, USING SAME	MITAMURA, NOBUAKI
<u>10410342</u>	7037386	150	04/10/2003	ROLLING BEARING FOR CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI

10414308	6923576	150	04/16/2003	ROLLING BEARING AND BELT CONTINUOUSLY VARIABLE TRANSMISSION	MITAMURA, NOBUAKI
10500580	Not Issued	41	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	MITAMURA, NOBUAKI
10510695	Not Issued	41	10/08/2004	METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND SILICON WAFER	MITAMURA, NOBUAKI
10512470	Not Issued	20	10/26/2004	Silicon single crystal wafer and epitaxial wafer, and method for producing silicon single crystal	MITAMURA, NOBUAKI

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Day : Wednesday

Date: 6/28/2006

Time: 06:35:23

PALM INTRANET**Inventor Name Search Result**

Your Search was:

Last Name = OHTA

First Name = TOMOHIKO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08655810	5817171	150	05/31/1996	APPARATUS AND METHOD FOR PRODUCING SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	OHTA, TOMOHIKO
08666654	5704973	150	06/18/1996	AN APPARATUS AND METHOD FOR THE UNIFORM DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL	OHTA, TOMOHIKO
08699719	5725661	250	07/01/1996	EQUIPMENT FOR PRODUCING SILICON SINGLE CRYSTALS	OHTA, TOMOHIKO
08760959	5766346	150	12/05/1996	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	OHTA, TOMOHIKO
08770499	5851283	150	12/20/1996	METHOD AND APPARATUS FOR PRODUCTION OF SINGLE CRYSTAL	OHTA, TOMOHIKO
08776776	5972106	150	02/10/1997	DEVICE AND METHOD FOR PRODUCING SINGLE CRYSTAL	OHTA, TOMOHIKO
08786340	5882398	250	01/23/1997	METHOD OF MANUFACTURING SINGLE CRYSTAL OF SILICON	OHTA, TOMOHIKO
08798472	5948163	250	02/10/1997	APPARATUS FOR MANUFACTURING CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD	OHTA, TOMOHIKO
09090400	5938842	150	06/04/1998	METHOD FOR PRODUCING A SINGLE CRYSTAL USING	OHTA, TOMOHIKO

				CZOCHRALSKI TECHNIQUE	
09125339	6071337	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	OHTA, TOMOHIKO
09270277	6153009	150	03/16/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL AND THE SILICON SINGLE CRYSTAL PRODUCED THEREBY	OHTA, TOMOHIKO
09270453	6156119	150	03/17/1999	SILICON SINGLE CRYSTAL AND METHOD FOR PRODUCING THE SAME	OHTA, TOMOHIKO
09290261	6117231	150	04/13/1999	METHOD OF MANUFACTURING SEMICONDUCTOR SILICON SINGLE CRYSTAL WAFER	OHTA, TOMOHIKO
09328278	6190452	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	OHTA, TOMOHIKO
09541462	7078203	150	03/31/2000	ISOLATED DNA ENCODING CULLIN REGULATORS ROC1 AND ROC2, ISOLATED PROTEIND ENCODED BY THE SAME, AND METHODS UTILIZING THE SAME	OHTA, TOMOHIKO
09646713	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBTRATE FOR EPITAXIAL SILICON WAFER	OHTA, TOMOHIKO
09673480	Not Issued	161	10/16/2000	Method for producing silicon single crystals	OHTA, TOMOHIKO
09674858	6423285	150	11/07/2000	Method for producing silicon single crystal and production apparatus therefor as well as crystal and silicon wafer produced by the method	OHTA, TOMOHIKO
09727275	6482260	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	OHTA, TOMOHIKO
09937132	6632280	150	09/21/2001	SINGLE CRYSTAL GROWING DEVICE	OHTA, TOMOHIKO
09959381	6592662	150	10/24/2001	METHOD FOR PREPARING	OHTA, TOMOHIKO

				SILICON SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL	
09959593	6605152	150	10/31/2001	CATCH PAN FOR MELT LEAKAGE IN APPARATUS FOR PULLING SINGLE CRYSTAL	OHTA, TOMOHIKO
09979519	6632411	150	11/23/2001	SILICON WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	OHTA, TOMOHIKO
10204278	6764548	150	08/20/2002	APPARATUS AND METHOD FOR PRODUCING SILICON SEMICONDUCTOR SINGLE CRYSTAL	OHTA, TOMOHIKO
10204935	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	OHTA, TOMOHIKO
10312921	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	OHTA, TOMOHIKO
10500580	Not Issued	41	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	OHTA, TOMOHIKO
10503721	Not Issued	41	08/06/2004	HEATER FOR MANUFACTURING A CRYSTAL	OHTA, TOMOHIKO
10510695	Not Issued	41	10/08/2004	METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND SILICON WAFER	OHTA, TOMOHIKO
10512470	Not Issued	20	10/26/2004	Silicon single crystal wafer and epitaxial wafer, and method for producing silicon single crystal	OHTA, TOMOHIKO
10561865	Not Issued	30	02/20/2006	Method for producing single crystal and single crystal	OHTA, TOMOHIKO
60127261	Not Issued	159	03/31/1999	ISOLATION OF ROC1 AND ROC2	OHTA, TOMOHIKO
60166927	Not Issued	159	11/22/1999	ISOLATED DNA ENCODING CULLIN REGULATORS ROC1 AND ROC2, ISOLATED PROTEINS ENCODED BY SAME, AND METHODS UTILIZING THE SAME	OHTA, TOMOHIKO

<u>60541287</u>	Not Issued	159	02/02/2004	Tumor suppressor BRCA1-BARD1 ubiquitinates nucleophosmin and is inhibited by CDK2	OHTA, TOMOHIKO
<u>60727429</u>	Not Issued	20	10/18/2005	Method for the ubiquitination of common subunits of RNA polymerases	OHTA, TOMOHIKO
<u>60750877</u>	Not Issued	20	12/16/2005	Functional interaction between BRCA1 and HERC2, a large protein deficient in rjs/jdf2 mice x: BRCA1 degradation by HERC2	OHTA, TOMOHIKO
<u>10261956</u>	6862014	150	10/01/2002	DISPLAY DRIVING APPARATUS AND DRIVING CONTROL METHOD	OHTANI, TOMOHIKO
<u>10415283</u>	Not Issued	30	04/28/2003	Display device and control system thereof	OHTANI, TOMOHIKO

Inventor Search Completed: No Records to Display.

Search Another: Inventor	Last Name	First Name
	<input type="text" value="Ohta"/>	<input type="text" value="Tomohiko"/>
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Day : Wednesday

Date: 6/28/2006
Time: 06:35:38**PALM INTRANET****Inventor Name Search Result**

Your Search was:

Last Name = FUSEGAWA

First Name = IZUMI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
06941624	Not Issued	161	12/11/1986	METHOD AND APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
07242414	4956153	250	09/09/1988	APPARATUS FOR CZOCHRALSKI SINGLE CRYSTAL GROWING	FUSEGAWA, IZUMI
07496750	5110404	150	03/21/1990	METHOD FOR HEAT PROCESSING OF SILICON	FUSEGAWA, IZUMI
07703750	Not Issued	166	05/21/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
07713848	5306387	150	06/12/1991	METHOD FOR PULLING UP SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
07729026	Not Issued	161	07/12/1991	METHOD FOR PULLING SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
07796385	5688319	150	11/22/1991	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
07850506	5262338	250	03/13/1992	METHOD FOR FABRICATION OF SEMICONDUCTOR DEVICE	FUSEGAWA, IZUMI
07850915	Not Issued	166	03/13/1992	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
07850916	5386796	150	03/13/1992	METHOD FOR TESTING QUALITY OF SILICON WAFER	FUSEGAWA, IZUMI
07852612	5248378	150	03/17/1992	METHOD AND APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
07953918	5359959	150	09/30/1992	METHOD FOR PULLING UP	FUSEGAWA, IZUMI

				SEMI-CONDUCTOR SINGLE CRYSTAL	
07961182	5462010	250	10/14/1992	APPARATUS FOR SUPPLYING GRANULAR RAW MATERIAL FOR A SEMICONDUCTOR SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
07961764	5373805	250	10/15/1992	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
08011744	5340434	250	02/01/1993	PROCESS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08012172	5361721	250	02/02/1993	SINGLE CRYSTAL PULLING APPARATUS	FUSEGAWA, IZUMI
08108285	Not Issued	166	08/19/1993	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
08190604	Not Issued	166	02/02/1994	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08238722	5534112	150	05/05/1994	METHOD FOR TESTING ELECTRICAL PROPERTIES OF SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08293214	Not Issued	166	08/19/1994	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
08395837	5501172	150	02/28/1995	METHOD OF GROWING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
08445029	Not Issued	166	05/19/1995	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
08510436	5720809	250	08/02/1995	CRUCIBLE FOR PULLING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08552164	Not Issued	166	11/02/1995	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL GROWN BY CZOCHRALSKI METHOD	FUSEGAWA, IZUMI
08699719	5725661	250	07/01/1996	EQUIPMENT FOR PRODUCING SILICON SINGLE CRYSTALS	FUSEGAWA, IZUMI
08754784	5938841	150	11/21/1996	DEVICE FOR PRODUCING SINGLE CRYSTAL	FUSEGAWA, IZUMI
08760959	5766346	150	12/05/1996	APPARATUS FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
08770499	5851283	150	12/20/1996	METHOD AND APPARATUS	FUSEGAWA, IZUMI

				FOR PRODUCTION OF SINGLE CRYSTAL	
08773351	5871583	150	12/26/1996	AN APPARATUS FOR PRODUCING SILICON CRYSTAL	FUSEGAWA, IZUMI
08916291	5834322	250	08/22/1997	HEAT TREATMENT OF SI SINGLE CRYSTAL	FUSEGAWA, IZUMI
09270277	6153009	150	03/16/1999	METHOD FOR PRODUCING A SILICON SINGLE CRYSTAL AND THE SILICON SINGLE CRYSTAL PRODUCED THEREBY	FUSEGAWA, IZUMI
09290261	6117231	150	04/13/1999	METHOD OF MANUFACTURING SEMICONDUCTOR SILICON SINGLE CRYSTAL WAFER	FUSEGAWA, IZUMI
09429343	6387466	150	10/28/1999	SINGLE-CRYSTAL SILICON WAFER	FUSEGAWA, IZUMI
09646713	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	FUSEGAWA, IZUMI
09673480	Not Issued	161	10/16/2000	Method for producing silicon single crystals	FUSEGAWA, IZUMI
09674858	6423285	150	11/07/2000	Method for producing silicon single crystal and production apparatus therefor as well as crystal and silicon wafer produced by the method	FUSEGAWA, IZUMI
09937132	6632280	150	09/21/2001	SINGLE CRYSTAL GROWING DEVICE	FUSEGAWA, IZUMI
09959381	6592662	150	10/24/2001	METHOD FOR PREPARING SILICON SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
09979519	6632411	150	11/23/2001	SILICON WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	FUSEGAWA, IZUMI
10204278	6764548	150	08/20/2002	APPARATUS AND METHOD FOR PRODUCING SILICON SEMICONDUCTOR SINGLE CRYSTAL	FUSEGAWA, IZUMI
10204935	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON	FUSEGAWA, IZUMI

				SINGLE CRYSTAL	
10312921	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	FUSEGAWA, IZUMI
10500580	Not Issued	41	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	FUSEGAWA, IZUMI
10510695	Not Issued	41	10/08/2004	METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE CRYSTAL AND SILICON WAFER	FUSEGAWA, IZUMI
10512470	Not Issued	20	10/26/2004	Silicon single crystal wafer and epitaxial wafer, and method for producing silicon single crystal	FUSEGAWA, IZUMI
10516347	Not Issued	20	11/30/2004	Graphite heater for producing single crystal, single crystal productin system and single crystal productin method	FUSEGAWA, IZUMI
10538878	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	FUSEGAWA, IZUMI
10542376	Not Issued	30	07/14/2005	AN SOI WAFER AND A METHOD FOR PRODUCING THE SAME	FUSEGAWA, IZUMI
10561865	Not Issued	30	02/20/2006	Method for producing single crystal and single crystal	FUSEGAWA, IZUMI
10568186	Not Issued	19	01/01/0001	Method for producing a single crystal and silicon single crystal wafer	FUSEGAWA, IZUMI

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PALM INTRANET**Inventor Name Search Result**

Your Search was:

Last Name = SAKURADA

First Name = MASAHIRO

Application#	Patent#	Status	Date Filed	Title	Inventor Name
08498894	5609682	150	07/06/1995	A METHOD FOR THE PREPARATION OF SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
08565100	5667584	150	11/30/1995	METHOD FOR THE PREPARATION OF A SINGLE CRYSTAL OF SILICON WITH DECREASED CRYSTAL DEFECTS	SAKURADA, MASAHIRO
08655810	5817171	150	05/31/1996	APPARATUS AND METHOD FOR PRODUCING SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO
08660198	5728211	250	06/03/1996	SILICON SINGLE CRYSTAL WITH LOW DEFECT DENSITY AND METHOD OF PRODUCING SAME	SAKURADA, MASAHIRO
08666654	5704973	150	06/18/1996	AN APPARATUS AND METHOD FOR THE UNIFORM DISTRIBUTION OF CRYSTAL DEFECTS UPON A SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
08768282	5730800	150	12/17/1996	FUSED SILICA GLASS CRUCIBLE	SAKURADA, MASAHIRO
08798472	5948163	250	02/10/1997	APPARATUS FOR MANUFACTURING CRYSTALS ACCORDING TO THE CZOCHRALSKI METHOD, AND CRYSTALS MANUFACTURED BY THE MANUFACTURING METHOD	SAKURADA, MASAHIRO
09090400	5938842	150	06/04/1998	METHOD FOR PRODUCING A SINGLE CRYSTAL USING CZOCHRALSKI TECHNIQUE	SAKURADA, MASAHIRO

<u>09125339</u>	6071337	150	08/13/1998	APPARATUS AND METHOD FOR PRODUCING CRYSTALS BY THE CZOCHRALSKI METHOD AND CRYSTALS PRODUCED BY THIS METHOD	SAKURADA, MASAHIRO
<u>09232561</u>	6174364	150	01/15/1999	METHOD FOR PRODUCING SILICON MONOCRYSTAL AND SILICON MONOCRYSTAL WAFER	SAKURADA, MASAHIRO
<u>09328278</u>	6190452	150	06/08/1999	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>09646713</u>	6565822	150	09/21/2000	EPITAXIAL SILICON WAFER, METHOD FOR PRODUCING THE SAME AND SUBSTRATE FOR EPITAXIAL SILICON WAFER	SAKURADA, MASAHIRO
<u>09727275</u>	6482260	150	11/30/2000	SILICON SINGLE CRYSTAL WAFER AND A METHOD FOR PRODUCING IT	SAKURADA, MASAHIRO
<u>10204935</u>	6913646	150	08/27/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR PRODUCING SILICON SINGLE CRYSTAL	SAKURADA, MASAHIRO
<u>10312921</u>	6893499	150	12/26/2002	SILICON SINGLE CRYSTAL WAFER AND METHOD FOR MANUFACTURING THE SAME	SAKURADA, MASAHIRO
<u>10500580</u>	Not Issued	41	07/01/2004	AN SOI WAFER AND A METHOD FOR PRODUCING AN SOI WAFER	SAKURADA, MASAHIRO
<u>10512470</u>	Not Issued	20	10/26/2004	Silicon single crystal wafer and epitaxial wafer, and method for producing silicon single crystal	SAKURADA, MASAHIRO
<u>10516347</u>	Not Issued	20	11/30/2004	Graphite heater for producing single crystal, single crystal productin system and single crystal productin method	SAKURADA, MASAHIRO
<u>10530557</u>	Not Issued	20	04/07/2005	Annealed wafer and annealed wafer manufacturing method	SAKURADA, MASAHIRO
<u>10538878</u>	Not Issued	41	06/14/2005	Method of producing p-doped silicon single crystal and p-doped n-type silicon single crystal wafer	SAKURADA, MASAHIRO
<u>10542376</u>	Not	30	07/14/2005	AN SOI WAFER AND A	SAKURADA,

	Issued			METHOD FOR PRODUCING THE SAME	MASAHIRO
10546693	Not Issued	20	08/22/2005	An soi wafer and a method for producing the same	SAKURADA, MASAHIRO
10560581	Not Issued	19	01/01/0001	Method for producing a single crystal and a single crystal	SAKURADA, MASAHIRO
10561205	Not Issued	20	02/03/2006	Process for producing single crystal and single crystal	SAKURADA, MASAHIRO
10561865	Not Issued	30	02/20/2006	Method for producing single crystal and single crystal	SAKURADA, MASAHIRO

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** CONTINUING DATA *****

This application is a 371 of PCT/JP04/07252 05/27/2004

** FOREIGN APPLICATIONS *****

JAPAN 2003-184838 06/27/2003

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 9	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 1
35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met				
Verified and Acknowledged Examiner's Signature	Initials			

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TITLE

Method for producing single crystal and single crystal

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